NSN 5961-00-501-0656

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



| | uivu |
|--|------------|
| View Online at https://aerobasegroup.com/nsn/5961-00-501-0656 | |
| Inclosure Material: | |
| Metal | |
| Overall Length: | |
| Between 0.170 inches and 0.210 inches | |
| Terminal Length: | |
| 0.500 inches | |
| Overall Diameter: | |
| Between 0.209 inches and 0.230 inches | |
| Function For Which Designed: | |
| Amplifier | |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: | |
| To-71 | |
| Component Name And Quantity: | |
| 2 transistor | |
| Mounting Method: | |
| Clip and terminal | |
| Terminal Circle Diameter: | |
| Between 0.095 inches and 0.105 inches | |
| Semiconductor Material: | |
| Silicon all transistor | |
| Voltage Rating In Volts Per Characteristic: | |
| 60.0 breakdown voltage, collector-to-emitter, base open all transistor and 60.0 collector to base voltage, dc all transistor and | 6.0 emitte |
| to base, rms all transistor | |
| Current Rating Per Characteristic: | |
| 30.00 milliamperes source cutoff current all transistor | |
| Power Rating Per Characteristic: | |
| 300.0 milliwatts small-signal input power, common-collector absolute all transistor | |
| Maximum Operating Tempurature Per Measurement Point: | |
| 200.0 degrees celsius junction | |
| Special Features: | |
| All transistor junction pattern arrangement: npn | |
| Terminal Type And Quantity: | |
| 6 uninsulated wire lead | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |